# MULTILAYERED LOW PASS MICROSTRIP FILTER USING CSRR

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#### Abstract

In the present paper a multilayered microstrip low pass filter using complementary split ring resonator is proposed. A design for prominent stop band characteristics with minimized ripples is presented, while maintaining the filter pass-band performance. By properly designing and integrating the complementary split ring resonators with the low pass filter, the proposed structure exhibit superior pass band and stop band characteristics by eliminating unwanted spurious signals. Since the literature is multi-layered, no structure is designed at the ground plane and the problem of distortion of ground plane structure while packaging is resolved. The measured results indicate that the proposed structure achieves significantly improved band characteristics with minimum distortion, when compared with the simulated one.

Keywords: Low Pass filter; Multilayered; Metamaterial; Complementary split ring resonator (CSRR) structure

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## **1. INTRODUCTION**

A microwave filter is a two port network used to control the frequency response at a certain point in a microwave system [1]. More specifically a low pass filter is a filter that passes low frequency signals but attenuates signals with frequencies higher than cut off frequency as shown in Fig.1. The paper describes about the design and fabrication of multilayered low pass filter by using microstrip layout which works at 2GHz.

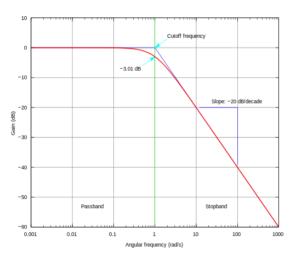


Fig. 1 Response of low pass filter

Recently, there has been a growing interest for the use of metamaterials in the development of compact microwave components constructed using printed circuit board technology. Metamaterials are artificial materials engineered to have properties that may not be found in nature. Metamaterial usually gain its properties from structure rather than composition, using small inhomogeneities to create effective macroscopic behavior. Specifically, the development of Complementary split ring resonators (CSRRs), originally proposed by Pendry et al. [2] was a major breakthrough for implementing left-handed techniques in planar circuit technology. Pendry et al. proposed that the frequency selective property of SRRs was due to the negative effective permeability, produced at resonance. Another interesting particle proposed is the complementary split ring resonator (CSRR) .This is a negative image of the SRR and hence is its dual counterpart. The CSRR behaves as an element, which is able to produce a negative effective permittivity at resonance. CSRRs can be etched in the ground plane, beneath the microstrip for stop band filter design and to eliminate the unwanted spurious signals. A general CSRR structure is shown in Fig. 2



Fig. 2 A general CSRR structure

Low-pass filters have been studied and exploited extensively as a key block in modern communication systems. A planar microwave filter is widely used in microwave systems because of its easy fabrication. According to microstrip theory, in order to control the characteristic impedance of a microstrip segment, the physical dimensions of the microstrip line are adjusted. The physical dimensions namely length (l) and width (w) depends on substrate thickness (d) and dielectric constant.

The paper describes about the design and fabrication of microwave low pass filter by using micro strip layout which resonates at 2.0GHz. It has been demonstrated that the selectivity of the filter increases and the filter size reduces by the use of multilayer structure. Since the design is multilayered, no structure is designed at the ground plane so the problem of distortion of ground plane structure while packaging and handling is resolved.

#### 2. FILTER DESIGNING

The proposed multi-layered low pass filter is designed and simulated using CST software with dielectric constant of 4.4 and substrate height of 1.67mm for a cut off frequency of 2.0GHz.

Richard's transformation and Kuroda's identities are used to translate a lumped element filter to a transmission line filter. Both identities are used to calculate the impedance of each transmission line segment based on its equivalent lumped element. In order to accommodate for Richard's Transformation and Kuroda's identities, it is essential to control the characteristic impedance of each lumped element or each transmission line segment.

The design of the low-pass micro strip filter having a resonant frequency 2.0GHz requires a series of steps. In order to design a low-pass filter with such specification it is required to design the filter using electronic circuit theory at normalized values. Further Richard's transformation is used to convert the series inductors to the equivalent series stubs, and the shunt capacitors to the equivalent shunt stubs. The Kuroda's identities are used to transform the series stubs into shunt stubs due to the difficulty of implementing series stubs in microstrip form. The lengths of the shunt stubs are frequency scaled to meet the cut off frequency requirement and the circuit is impedance scaled to 50. Subsequently, the filter's segments are converted into microstrip stubs using microstrip theory. The proposed microstrip filter is then designed and simulated using CST software and fabricated to compare the results.

On top layer a ninth order microstrip low pass filter is designed at a resonant frequency 2.0 GHz. Circuit diagram of a low pass filter with lumped element is shown in Fig. 3.

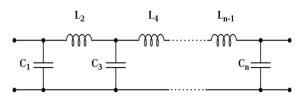


Fig. 3 Circuit diagram of low pass filter

In order to design the microstrip low pass filter with a 3dB ripple, the first step is to model the microstrip using electronic circuit theory. The normalized prototype low pass filter values are tabulated in Table 1.

Table 1 Normalized Low Pass Prototype Element Values

| g1 | 1.1957  | C1 |
|----|---------|----|
| g2 | 1.1426  | L2 |
| g3 | 2.1346  | C3 |
| g4 | 1.16167 | L4 |
| g5 | 2.2054  | C5 |
| g6 | 1.16167 | L6 |
| g7 | 2.1346  | C7 |
| g8 | 1.1426  | L8 |
| g9 | 1.0     | C9 |

The lumped values are further converted into distributed elements by using Richard's and Kuroda's identities. The impedance of each stub, excluding the center shunt stub, are multiplied by a factor so that the impedances of the stubs are equivalent to those as shown in Fig. 4.

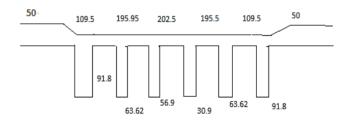


Fig. 4 Low pass filter showing required impedance values

The values of length (l) and width (w) of series and shunt stubs are calculated using the following equations [3]:

For W/h  $\leq 2$ 

$$\frac{W}{h} = \frac{8 \exp(A)}{\exp(2A) - 2} \tag{1}$$

With

$$A = \frac{Z_c}{60} \left\{ \frac{\varepsilon_r + 1}{2} \right\}^{1.5} + \frac{\varepsilon_r - 1}{\varepsilon_r + 1} \left\{ 0.23 + \frac{0.11}{\varepsilon_r} \right\}$$
(2)

And for  $W/h \geq 2$ 

$$\frac{W}{h} = \frac{2}{\pi} \left\{ (B-1) + \ln(2B-1) + \frac{\epsilon_r - 1}{2\epsilon_r} \left[ \ln(B-1) + 0.39 - \frac{0.61}{\epsilon_r} \right] \right\}$$
(3)

With

$$B = \frac{60\pi^2}{Z_c\sqrt{\epsilon_r}} \tag{4}$$

The calculated values of length and width of the proposed microstrip low pass filter corresponding to their impedances are tabulated in Table II.

Table 2 Calculated Values Of Length And Width

| Impedance(ohm) | Length(mm) | Width(mm) |
|----------------|------------|-----------|
| 50             | 10.275     | 3.0599    |
| 91.8           | 10.7175    | .890836   |
| 109.75         | 10.85625   | .5416     |
| 63.625         | 9.9675     | 1.9976    |
| 195.95         | 11.2275    | .050929   |
| 56.9           | 10.365     | 2.4524    |
| 202.45         | 11.2425    | .04262    |
| 30.9           | 9.7575     | 9.90406   |

The proposed low pass filter is designed on top layer using CST software as shown in Fig. 5(a) and hardware design in Fig. 5(b), where the series stub represent inductance and shunt stub represent capacitance.

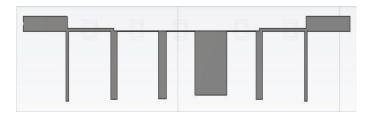


Fig. 5(a) Top layer with proposed low pass filter



Fig. 5(b) Top layer view of proposed low pass filter

And the CSRR structures are simulated on the middle layer as shown in Fig. 6.

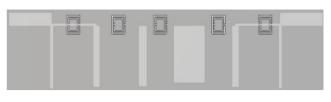


Fig. 6(a) Middle layer with CSRR structure



Fig. 6(b) Hardware design of middle layer with CSRR structure

### 3. RESULTS AND DISCUSSION

The design of the multilayered microstrip low pass filter with a resonant frequency 2.0 GHz with low pass structure on the top layer, CSRR on the middle layer and an empty ground layer is designed and simulated.

Two glass epoxy printed circuit boards were patterned, stacked and attached closely for fabrication of the proposed filter. A photograph of the fabricated low pass filter is shown in Fig.7.

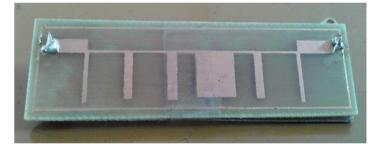


Fig. 7(a) Photograph of fabricated low pass filter (top view)

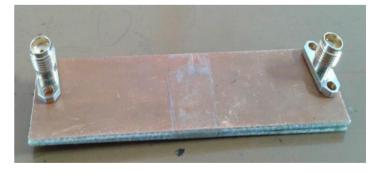
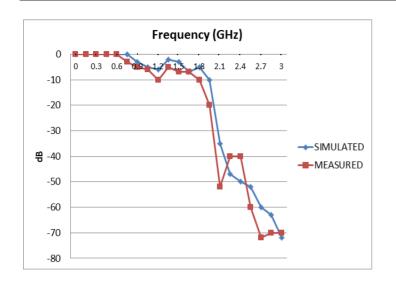
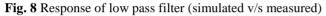


Fig. 7(b) Photograph of fabricated low pass filter (bottom view)

The filter responses obtained by simulating using CST and hardware are in close approximation with each other as shown in Fig. 8.





From Fig. 8 it can be seen that the filter has a pass band from 0 to 2.0GHz. The filter has approximately zero ripples in pass band and in stop band as suggested by the property of CSRR structures. As can be seen, the simulated and measured results are well in accordance with each other. The measured result shows a gain of -53dB whereas the simulated result shows a gain of -35dB. Thus inferring that that the fabricated filter has a better performance as compared to the simulated one. Thus the overall performance of the final design of the multilayered microstrip low pass filter easily met the proposed requirements.

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## BIOGRAPHIES



Prachi Agrawal received her B.Tech. Degree from Gautam Buddha Technical University, India, in 2012 And she is currently working toward the M.Tech. Degree in Microwave Engineering from Madhav Institute of Science and Technology, India Her research interest

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